

# Renjie Wang

## List of Publications by Year in descending order

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29  
papers

464  
citations

840776

11  
h-index

713466

21  
g-index

29  
all docs

29  
docs citations

29  
times ranked

648  
citing authors

#	ARTICLE	IF	CITATIONS
1	Full-Color Single Nanowire Pixels for Projection Displays. Nano Letters, 2016, 16, 4608-4615.	9.1	151
2	Color-tunable, phosphor-free InGaN nanowire light-emitting diode arrays monolithically integrated on silicon. Optics Express, 2014, 22, A1768.	3.4	82
3	High efficiency, full-color AlInGaN quaternary nanowire light emitting diodes with spontaneous core-shell structures on Si. Applied Physics Letters, 2015, 106, .	3.3	42
4	Epitaxial Growth and Characterization of AlInN-Based Core-Shell Nanowire Light Emitting Diodes Operating in the Ultraviolet Spectrum. Scientific Reports, 2020, 10, 2547.	3.3	23
5	Submicron full-color LED pixels for microdisplays and micro-LED main displays. Journal of the Society for Information Display, 2020, 28, 410-417.	2.1	22
6	Decoupling Strategy for Enhanced Syngas Generation from Photoelectrochemical CO2 Reduction. IScience, 2020, 23, 101390.	4.1	19
7	Optically invariant InGaN nanowire light-emitting diodes on flexible substrates under mechanical manipulation. Npj Flexible Electronics, 2019, 3, .	10.7	18
8	High mobility single-crystalline-like germanium thin films on flexible, inexpensive substrates. Thin Solid Films, 2013, 527, 9-15.	1.8	16
9	Tunable, full-color nanowire light emitting diode arrays monolithically integrated on Si and sapphire. Proceedings of SPIE, 2016, , .	0.8	14
10	Enhancing the light extraction efficiency of AlInN nanowire ultraviolet light-emitting diodes with photonic crystal structures. Optics Express, 2020, 28, 22908.	3.4	14
11	Erbium-ytterbium co-doped aluminium oxide waveguide amplifiers fabricated by reactive co-sputtering and wet chemical etching. Optics Express, 2020, 28, 30130.	3.4	13
12	Molecular Beam Epitaxy of III-Nitride Nanowires: Emerging Applications From Deep-Ultraviolet Light Emitters and Micro-LEDs to Artificial Photosynthesis. IEEE Nanotechnology Magazine, 2019, 13, 6-16.	1.3	10
13	Demonstration of infrared nBn photodetectors based on the AlInAsSb digital alloy materials system. Applied Physics Letters, 2021, 119, .	3.3	7
14	Prefabricated Metal Nanorods on Biaxially-Textured Templates on Flexible Substrates for REBCO Superconductors. IEEE Transactions on Applied Superconductivity, 2013, 23, 6600705-6600705.	1.7	5
15	Al <sub>0.3</sub> InAsSb/Al <sub>0.7</sub> InAsSb Digital Alloy nBn Photodetectors. Journal of Lightwave Technology, 2022, 40, 113-120.	4.6	5
16	Characterizing the electrical breakdown properties of single n-i-n <sup>+</sup> :GaN nanowires. Applied Physics Letters, 2018, 113, .	3.3	4
17	Epitaxial growth of (100) GaAs on CeOx coated flexible metal substrates. , 2012, , .		3
18	Dilute-antimonide GaSbN/GaN dots-in-wire heterostructures grown by molecular beam epitaxy: Structural and optical properties. Applied Physics Letters, 2021, 118, .	3.3	3

#	ARTICLE	IF	CITATIONS
19	Polarization-Engineered p-Type Electron-Blocking-Layer-Free III-Nitride Deep-Ultraviolet Light-Emitting Diodes for Enhanced Carrier Transport. <i>Journal of Electronic Materials</i> , 2022, 51, 838-846.	2.2	3
20	Multi-color nanowire LEDs on a single chip. , 2017, , .		2
21	30 <sup>th</sup> : Distinguished Paper: Sub-Micron Full-Color LED Pixels for Micro-Displays and Micro-LED Main Displays. <i>Digest of Technical Papers SID International Symposium</i> , 2020, 51, 432-435.	0.3	2
22	Novel single-crystalline-like germanium thin films on flexible, inexpensive substrates: Influence of architecture and film thickness. , 2011, , .		1
23	Color Tunable Phosphor-Free InGaN/GaN/AlGaIn Core-Shell Nanowire Light-Emitting Diodes on Silicon. , 2014, , .		1
24	InGaIn nanowire integrated nanophotonics. , 2017, , .		1
25	Selective area grown AlInGaIn nanowire arrays with core-shell structures for photovoltaics on silicon. <i>Nanoscale</i> , 2021, 13, 8163-8173.	5.6	1
26	An SEM-Based Nanomanipulation System for Multi-Physical Characterization of Single InGaIn/GaN Nanowires. , 2020, , .		1
27	Infrared Al <sub>0.15</sub> InAsSb Digital Alloy <i>Nbn</i> Photodetectors. <i>Journal of Lightwave Technology</i> , 2022, 40, 3855-3863.	4.6	1
28	Optimization of a single crystalline-like germanium thin film growth on inexpensive flexible substrates and fabrication of germanium bottom junction. , 2013, , .		0
29	(Invited) High Efficiency, Color-Tunable InGaIn/GaN Nanowire Light Emitting Diode Arrays. <i>ECS Meeting Abstracts</i> , 2016, , .	0.0	0